

Product data sheet

1. General description

Planar passivated AC Thyristor Triac power switch in a SOT186A (TO-220F) "full pack" plastic package with self-protective capabilities against low and high energy transients.

2. Features and benefits

- Clamping structure ensuring safe high over-voltage withstand capability
- Direct interfacing with low power drivers and microcontrollers
- Full cycle AC conduction
- Isolated mounting base package
- Over-voltage withstand capability to IEC 61000-4-5
- Pin compatible with standard triacs
- Planar passivated for voltage ruggedness and reliability
- Safe clamping capability for low energy over-voltage transients
- Self-protective turn-on during high energy voltage transients
- Sensitive gate for easy logic level triggering
- Triggering in three quadrants only
- Very high immunity to false turn-on by dV/dt

3. Applications

- AC fan, pump and compressor controls
- Highly inductive, resistive and safety loads
- Large and small appliances (White Goods)
- Reversing induction motor controls

4. Quick reference data

| Table 1. Qu | ick reference data | | | | | |
|---------------------|--|---|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| V _{DRM} | repetitive peak off- state voltage | | - | - | 800 | V |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{ Fig. 4}; \text{ Fig. 5}$ | - | - | 14 | A |
| Tj | junction temperature | | - | - | 125 | °C |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _h ≤ 106 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u> | - | - | 2 | A |





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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|---|-----|-----|-----|------|
| V _{PP} | peak pulse voltage | T _j = 25 °C; non-repetitive, off-state; Fig. 6 | - | - | 2 | kV |
| Static chara | acteristics | · · · · · | I | | | |
| I _{GT} | gate trigger current | $V_D = 12 \text{ V}; \text{ I}_T = 100 \text{ mA}; \text{ LD+ G+};$ $T_j = 25 \text{ °C}; \text{ Fig. 8}$ | - | - | 10 | mA |
| | | V _D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 8</u> | - | - | 10 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_T = 100 \text{ mA}; \text{ LD- G-};$ $T_j = 25 \text{ °C}; \text{ Fig. 8}$ | - | - | 10 | mA |
| V _{CL} | clamping voltage | I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C | 850 | - | - | V |
| Dynamic cl | naracteristics | | I | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 13 | 500 | - | - | V/µs |
| dI _{com} /dt | rate of change of commutating current | V_D = 400 V; T _j = 125 °C; I _{T(RMS)} = 2 A; dV _{com} /dt = 10 V/µs; gate open circuit; Fig. 14; Fig. 15 | 3 | - | - | A/ms |

5. Pinning information

| Table 2. | Pinning | information | | |
|----------|---------|-------------------------|-------------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | T1 | main terminal 1 | mb | T2 |
| 2 | Т2 | main terminal 2 | | sym051 |
| 3 | G | gate | | |
| mb | n.c. | mounting base; isolated | | |
| | | | | |
| | | | $ \bigcup_{1 \ 2 \ 3} $ | |
| | | | TO-220F (SOT186A) | |

6. Ordering information

| Table 3. Ordering information | | | | | | | |
|-------------------------------|---------|---|---------|--|--|--|--|
| Type number | Package | | | | | | |
| | Name | Description | Version | | | | |
| ACTT2X-800E | TO-220F | plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack" | SOT186A | | | | |

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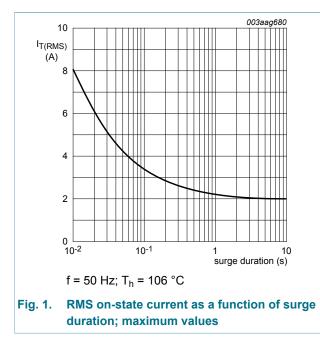
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7. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|--------------------------------------|---|-----|------|------------------|
| V _{DRM} | repetitive peak off-state voltage | | - | 800 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_h \le 106 \text{ °C}$; Fig. 1; Fig. 2; Fig. 3 | - | 2 | A |
| I _{TSM} | non-repetitive peak on-state current | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms | - | 15.4 | A |
| | | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{ Fig. 4}; \text{ Fig. 5}$ | - | 14 | A |
| l ² t | I ² t for fusing | t _p = 10 ms; sine-wave pulse | - | 0.98 | A ² s |
| dl _T /dt | rate of rise of on-state current | I_T = 3 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs | - | 100 | A/µs |
| I _{GM} | peak gate current | t = 20 μs | - | 2 | А |
| P _{GM} | peak gate power | | - | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.5 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| Tj | junction temperature | | - | 125 | °C |
| V _{PP} | peak pulse voltage | T _j = 25 °C; non-repetitive, off-state; Fig. 6 | - | 2 | kV |



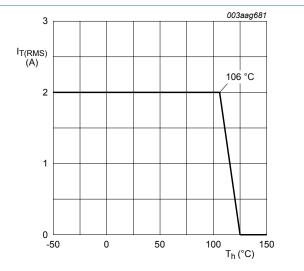
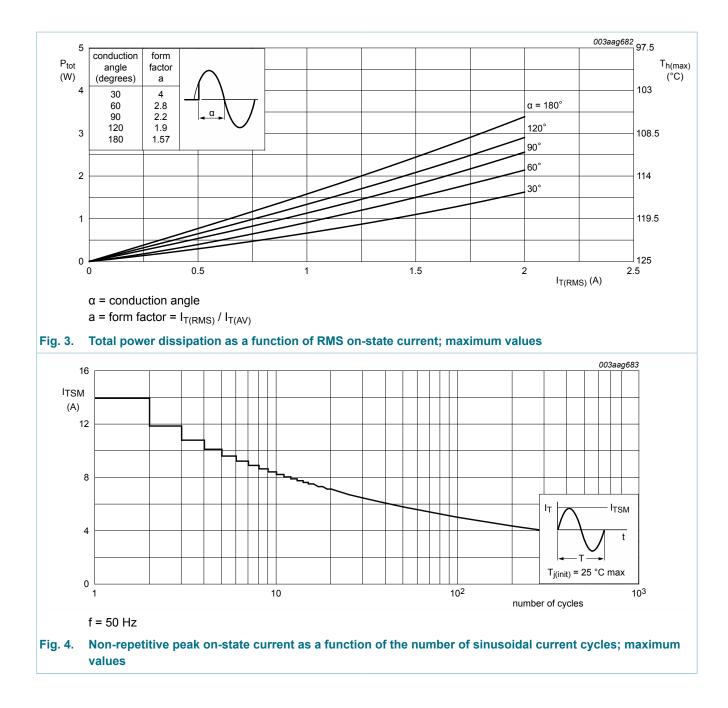


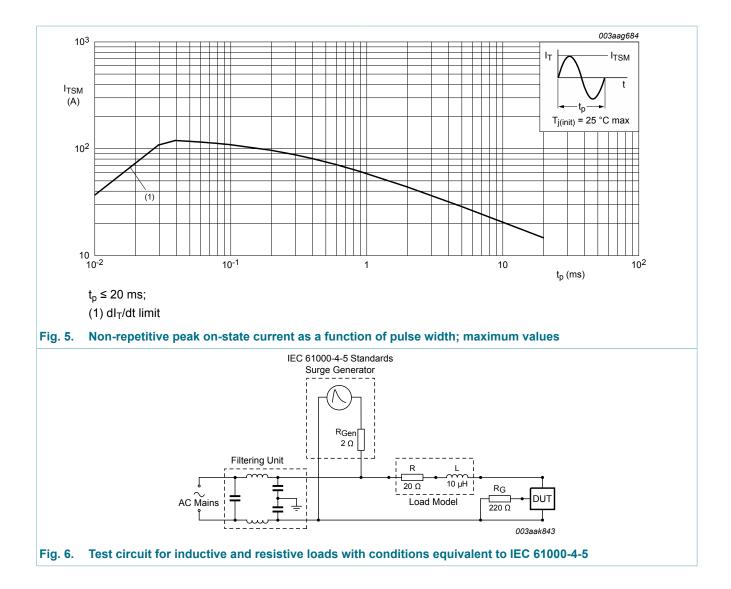
Fig. 2. RMS on-state current as a function of heatsink temperature; maximum values

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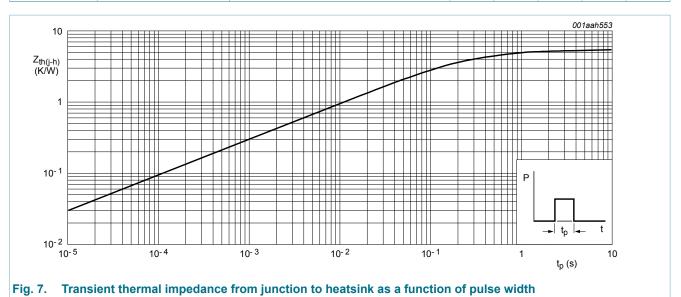
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8. Thermal characteristics

| Table 5. 1 | Thermal characteristics | | | | | |
|----------------------|--|---|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| R _{th(j-h)} | thermal resistance from junction to heatsink | full or half cycle with heatsink compound; Fig. 7 | - | - | 5.5 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | - | 55 | - | K/W |



9. Isolation characteristics

| Table 6. Isolation characteristics | | | | | | | | |
|------------------------------------|-----------------------|---|--|-----|-----|------|------|--|
| Symbol | Parameter | Conditions | | Min | Тур | Мах | Unit | |
| V _{isol(RMS)} | RMS isolation voltage | 50 Hz \leq f \leq 60 Hz; RH \leq 65% RH; T _h = 25 °C; from all terminals to external heatsink; sinusoidal waveform; clean and dust free | | - | - | 2500 | V | |
| C _{isol} | isolation capacitance | f = 1 MHz; T_h = 25 °C; from main terminal 2 to external heatsink | | - | 10 | - | pF | |

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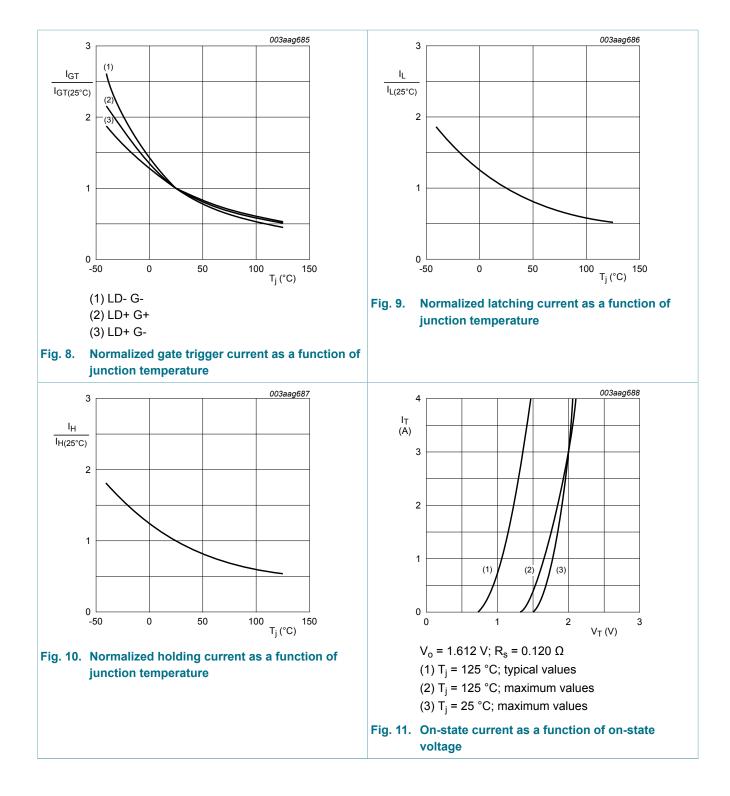
10. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|--|-----|------|-----|------|
| Static chara | cteristics | · · · · | | | | |
| I _{GT} | gate trigger current | $V_D = 12 \text{ V}; I_T = 100 \text{ mA}; \text{LD+ G+};$ $T_j = 25 \text{ °C}; Fig. 8$ | - | - | 10 | mA |
| | | V _D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 8</u> | - | - | 10 | mA |
| | | V _D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 8</u> | - | - | 10 | mA |
| L | latching current | V _D = 12 V; I _G = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 9</u> | - | - | 25 | mA |
| | | V _D = 12 V; I _G = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 9</u> | - | - | 35 | mA |
| | | V _D = 12 V; I _G = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 9</u> | - | - | 25 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u> | - | - | 25 | mA |
| V _T | on-state voltage | I _T = 3 A; T _j = 25 °C; <u>Fig. 11</u> | - | - | 2 | V |
| V _{GT} | gate trigger voltage | V _D = 12 V; I _T = 100 mA; T _j = 25 °C; Fig. 12 | - | 0.8 | 1 | V |
| | | V _D = 400 V; I _T = 100 mA; T _j = 125 °C; Fig. 12 | 0.2 | 0.45 | - | V |
| D | off-state current | V _D = 800 V; T _j = 25 °C | - | - | 10 | μA |
| | | V _D = 800 V; T _j = 125 °C | - | - | 0.5 | mA |
| V _{CL} | clamping voltage | I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C | 850 | - | - | V |
| Dynamic ch | aracteristics | · · · · | | - 1 | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 13 | 500 | - | - | V/µs |
| dl _{com} /dt | rate of change of commutating current | $V_D = 400 \text{ V}; \text{ T}_j = 125 \text{ °C}; \text{ I}_{T(RMS)} = 2 \text{ A};$ $dV_{com}/dt = 10 \text{ V}/\mu\text{s}; \text{ gate open circuit};$ Fig. 14; Fig. 15 | 3 | - | - | A/m |

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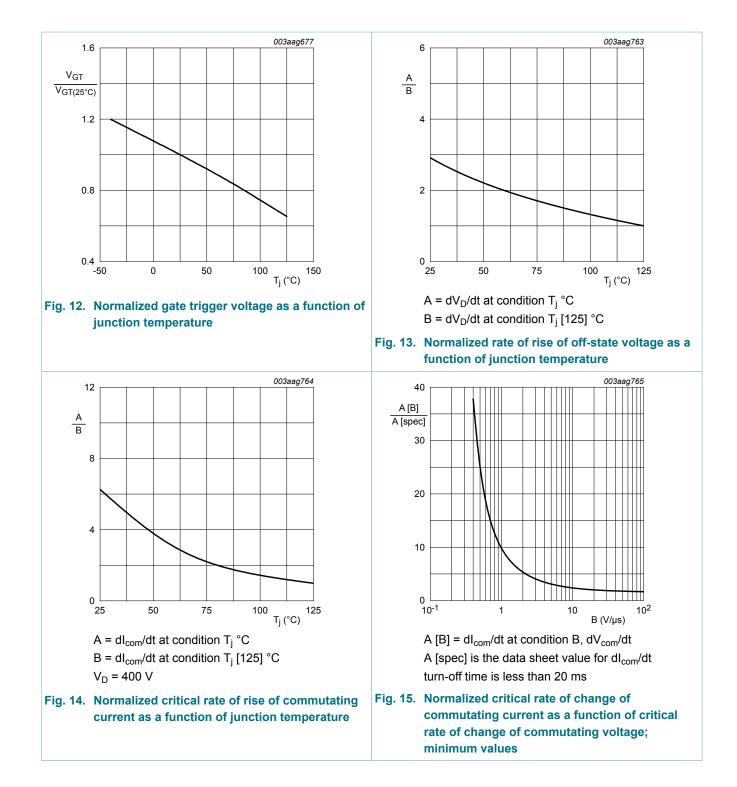


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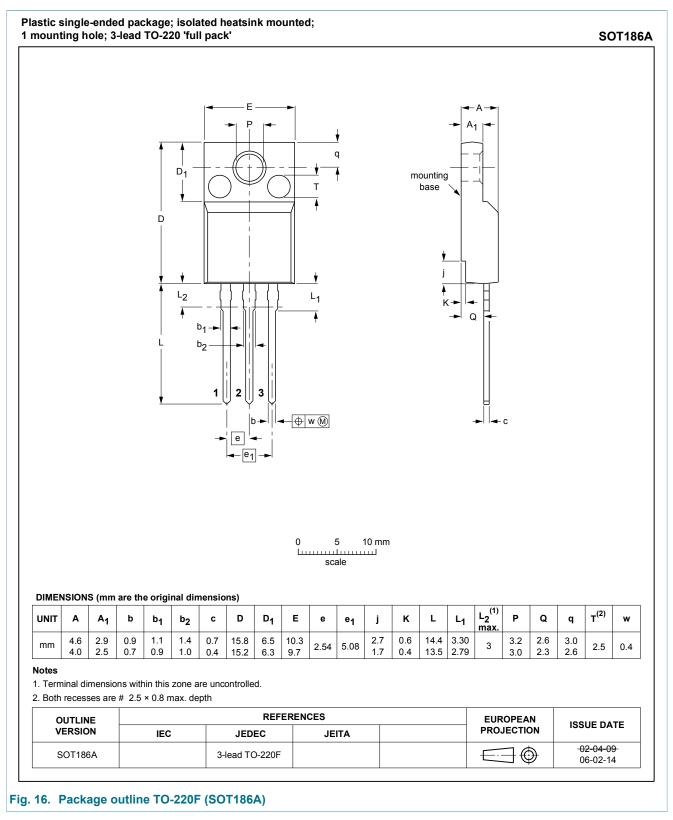
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11. Package outline



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| _ | | |
|--------------------------------------|-----------------------|---|
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